

## Closed Loop Sic-Based Z-Source Resonant Converter Using Phase Shift Control for EV Wireless Charger

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**Abstract:** Traditional load regulation methods for a resonant converter mainly rely on frequency modulation. It is always a tradeoff between the design of the resonant network and the range of load. Especially for wireless power transfer (WPT) systems, the resonant network usually has a high quality factor. Small variation on frequency leads to huge drop in gain and efficiency. Due to this problem, many WPT systems are unregulated and they need one or two more front-end stages to regulate the dc bus voltage and perform power factor correction (PFC). In order to lower the cost and complexity of two- or three-stages structure, a single-stage solution with a silicon carbide (SiC) based Z-source resonant converter (ZSRC) was recently proposed. The Z-source network provides high reliability as being immune to shoot-through problems. Additionally, a ZSRC can boost the dc bus voltage while the traditional voltage-source inverter can only produce a lower volt-age. However, the load regulation of this new topology has not been addressed. Two effective load regulation methods with constant frequency are presented for this SiC-based ZSRC specifically. Operation principle of the two load regulation methods are described in this paper. Experimental results based on a 200-W scale-down prototype with a full-bridge series resonant dc-dc converter are presented to illustrate the mechanism of these two methods.

**Index Terms:** Electric vehicles (EVs), load regulation, resonant converter, silicon carbide (SiC), wireless power transfer (WPT), Z-source.

### I. Introduction

Research on wireless power transfer (WPT) for the electric vehicles (EVs) battery charger is actively carrying on, for the sake of its advantages of convenience, reliability, and environmental adaptation [1]. For a stationary application, a WPT charger system allows the driver simply to park and charge without getting out of the vehicle. Furthermore, a dynamic WPT charger system, also called online inductive power transfer (OLPT), can charge the running EVs with embedded transmit coils under a road (see Fig. 1). A proper energy storage and charging system design could reduce 20% battery capacity of the EVs [2].

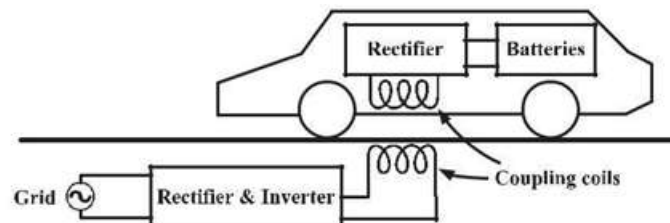


Fig. 1. Configuration of a WPT system for OLPT.

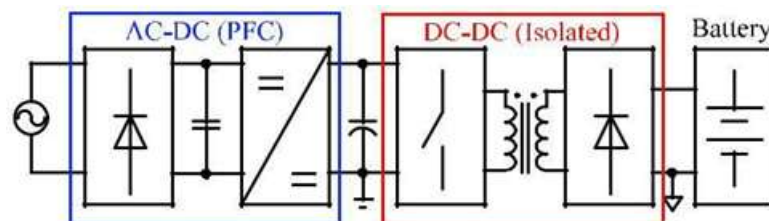


Fig. 2. Block diagram of a conventional OBC.

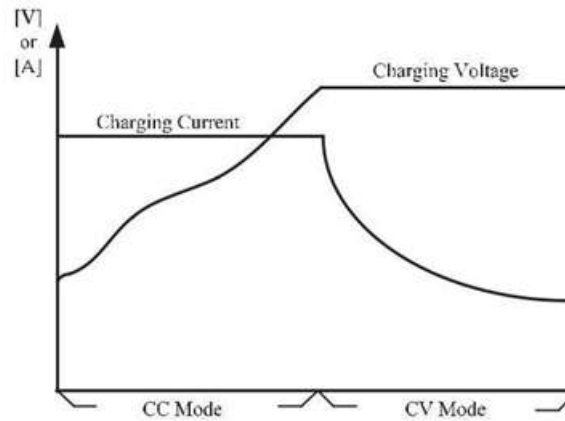


Fig. 3. OBC charging mode.

A conventional on-board battery charger (OBC) is usually a two-stage structure; a power factor correction (PFC) front-end part and a dc–dc converter part with high-frequency transformer, as shown in Fig. 2. Load regulation function is required for the dc–dc converter as the battery charger has constant current (CC) mode and constant voltage (CV) mode, as shown in Fig. 3. In order to shorten the charging time, the people are no longer satisfied

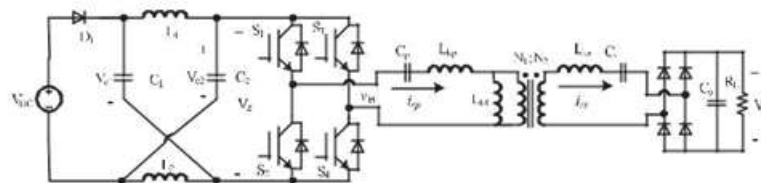


Fig. 4. Circuit schematic of the ZSRC.

that the low-medium load range in CV mode consumes 40% of the total charge time [4]. In other words, load regulation in CV mode is essential in terms of the overall performance of the OBC.

In WPT application, the series resonant dc–dc converter (SRC) is widely adopted as the dc–dc converter because of its simplicity and high efficiency [5]. An SRC, like other resonant converters, can realize load regulation by frequency modulation method (PFM). However, owing to the large ratio between the leakage inductance and magnetizing inductance (greater than 10:1) in WPT application, an SRC has a high quality factor. Small drift away from resonant frequency leads to huge drop in gain and huge increment in circulating current [6]. In [7] and [8], from Oak Ridge National Laboratory, an SRC is investigated and verified that the peak power range is broader for a given frequency band and then drops quickly outside the band. In their later work [9], they change to series–parallel configuration that has a wider plateau in the power versus frequency curve, which gives them more freedom on PFM control.

Two or more stage solutions are of high cost and complicated, even though the design for each stage is simple. The overall performance may not be the best. A Z-source inverter [17], well known for its boost feature and being immune to shoot-through problem, can be applied to any kind of power conversion between dc and ac. A combination of Z-source network (ZSN) and SRC has been studied in [18]. It can improve the efficiency over a wide input voltage and load variation. Furthermore, a Z-source resonant converter (ZSRC) was proposed in [32] and proved its advantage over conventional boost PFC with a cascaded dc–dc. Fig. 4 shows the overall schematic for a ZSRC. The input diode is a silicon carbide (SiC) device with almost zero reverse recovery loss which is a previous headache for a Z-source inverter in many applications. A ZSN is placed between the input diode and the H-bridge inverter of the conventional SRC system. The original Z-source topology is chosen as it can share the input diode with the diode bridge when connecting to the ac source. The SRC converts the dc power to high frequency ac power and pass it to the secondary side. This is a single-stage solution that saves the cost and complicity. And the load regulation method for the ZSRC has not been addressed. In terms of Z-source, plenty of re-research on the control has been done for the dc–dc converter [19]–[25]. In one switching period, the load current that the inverter draws is modeled as a CC source. However, in a resonant converter, the load current is sinusoidal over one switching period which makes everything interesting. Those conventional control

schemes pay attention to the duty cycle of shoot-through state only, while the position of shoot-through state in one switching period is also crucial for the resonant converter. In [29], the shoot-through state is evenly distributed over one cycle and it results in less voltage ripple on a dc-link capacitor. A control method [30] with shoot-through state right after active state can provide soft switching at turn-on action. In this paper, for the ZSRC specifically, two constant frequency control methods—phase-shift method and pulse notch method are discussed. The pulse notch control method can theoretically regulate the load downward all the way to zero like a buck-type converter, which is a unique feature of the ZSRC. Pulse notch control is a better candidate for PFC function to achieve high power factor. A circuit description, analysis, and experimental results based on a 200-W scale-down prototype are provided in the following sections.

## II. ZSRC WPT System

Different from dc/ac application, the ZSRC has more states in one switching cycle. It is important to clarify all these states to understand the ZSRC. The boost ratio of ZSN is still related to the total shoot-through state duty cycle among these states. In this section, the operation principle of the ZSRC is described based on an example of the phase-shift control method. The mechanism of pulse notch control is presented after this.

### A. Operation Principle of a ZSRC WPT System

1) *Active State*: During the two active states time interval [see Fig. 5(c) and (g)], the diagonal switches are on, and the input

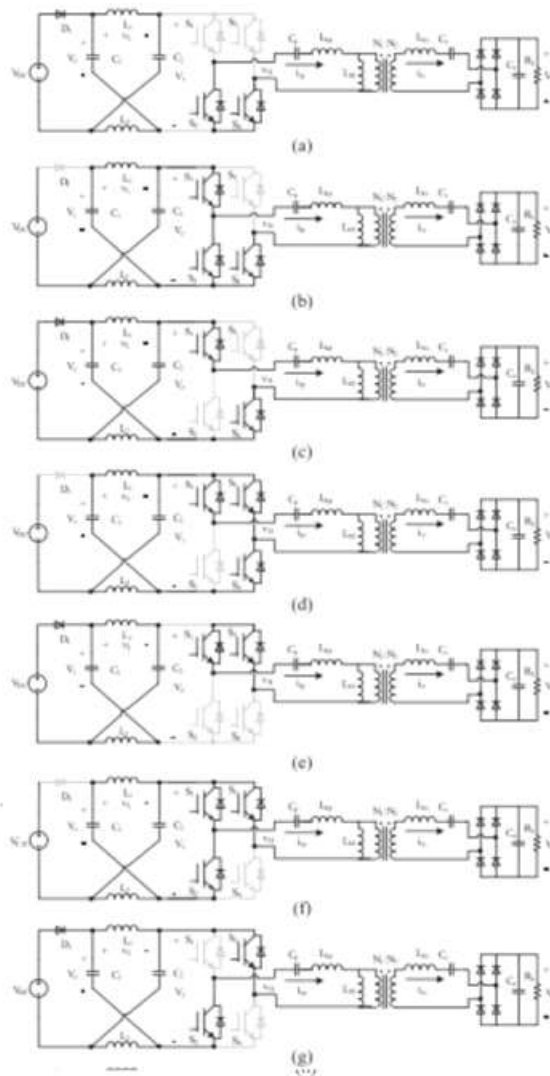
side diode  $D_1$  is conducting. The resonant network draws current from both the ZSN inductor and capacitor. The difference between load current ( $i_{lp}$ ) and ZSN inductor current ( $I_L$ ) is provided by a series connection of the two ZSN capacitor

2) *Shoot-Through State*: Four shoot-through state's time intervals are demonstrated in Fig. 5(b), (d), (f), and (h). Three of the switches are ON. The two horizontal switches are carrying the load current and the switches in one-phase leg are carrying the ZSN inductor current. Hence, there is one switch carrying the sum of the two currents.

3) *Zero State*: During the zero state's time interval [see Fig. 5(a) and (e)], two horizontal switches are ON. The ZSN is isolated from the load. The load current is freewheeling and the ZSN inductors charge the ZSN capacitors.

4) The relationship in (6) gives us a hint that the voltage on the ZSN capacitor is irrelevant to active state duty cycle  $D_{act}$ .

6) These three states are all the possible states in the ZSRC. Different allocations of these three states along one switching period would generate different load regulation characteristics. In next section, pulse notch control will be presented.



**Fig. 5.** ZSRC circuit diagram in different states: (a) zero state,  $t_0 - t_1$  and  $t_8 - t$ ; (b) shoot-through state,  $t_1 - t_2$ ; (c) active state,  $t_2 - t_3$ ; (d) shoot-through state,  $t_3 - t_4$ ; (e) zero state,  $t_4 - t_5$ ; (f) shoot-through state,  $t_5 - t_6$ ; (g) active state,  $t_6 - t_7$ ; and (h) shoot-through state,  $t_7 - t_8$ .

**B. Mechanism of Pulse Notch Control for a ZSRC WPT System**

In phase-shift control, different phase shifts actually generate different amplitudes of the fundamental component at switching frequency. Thus, controlling a notch width shares a similar idea, as Fig. 7 shows. Pulse notch control is usually used in a three-phase system [27], as it does not damage the symmetry of the three-phase system. In the case of a single-phase ZSRC, this notch can be either shoot-through state or zero state, which is illustrated in Fig. 7(a) and (b), respectively. Fig. 7 shows less state change than Fig. 6, and the detail description of each state is not repeated here.

The shoot-through notch will increase the output power as the boost from the shoot-through state surpasses the loss in active state. The mathematic explanation will be expanded in the next section. The original control signals (S10, S20, S30, and S40) come from a 50% duty cycle with constant frequency PWM signal

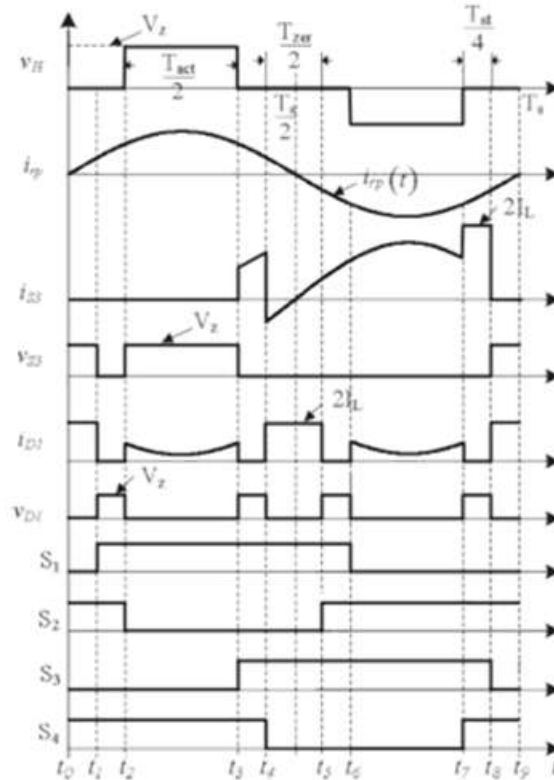


Fig 6. Time domain waveforms for phase-shift control in the ZSRC.

11 When the shoot-through control signal  $S_{sh}$  is high, all the gate signals are forced high as  $t1 - t2$  and  $t4 - t5$  in Fig. 7(a). The shoot-through notch is placed in the middle of active state for the sake of symmetry.

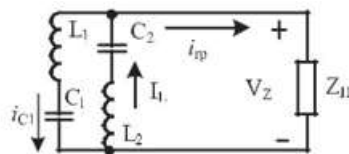
13 Fig. 7(b) shows another kind of notch. Zero state is filled in the middle of active state. Zero notches will help regulating the output power downward. The control concept is similar to the previous one. The original control signals ( $S_{10}$ ,  $S_{20}$ ,  $S_{30}$ , and  $S_{40}$ ) come from a 50% duty cycle with constant frequency PWM signal.

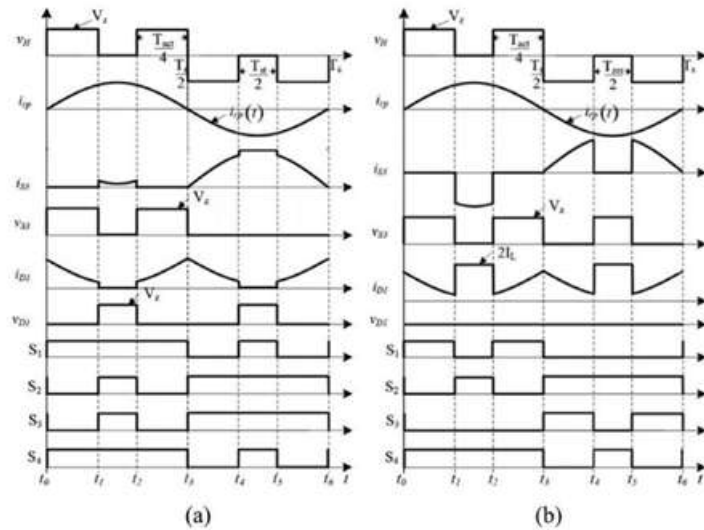
### III. Load Regulation For A Zsrc Wpt System

As mentioned in the previous section, the load current is limited by the ZSN inductor current in active state. As the load current is sinusoidal, the peak value of the load current may easily reach the limitation ( $2I_L$ ) and the output voltage  $v_H$  will collapse, which is called the discontinuous mode. Based on continuous mode or discontinuous mode of output voltage, this section is organized as follows: Section III-A describes the output power regulation under continuous mode; in Section III-B, the boundary of discontinuous mode will be developed; the power correction for discontinuous mode and the power loss analysis have been discussed in Sections III-C and III-D, respectively.

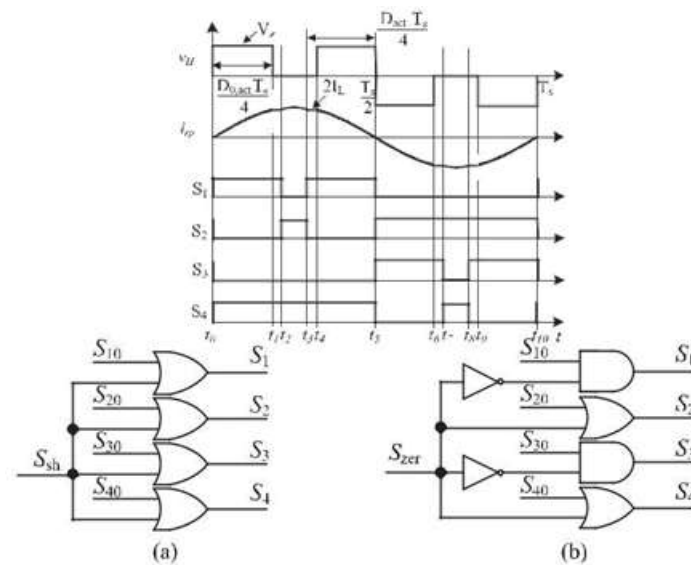
#### A. Output Power Regulation for a ZSRC WPT System

In order to get the output power derivation, the WPT

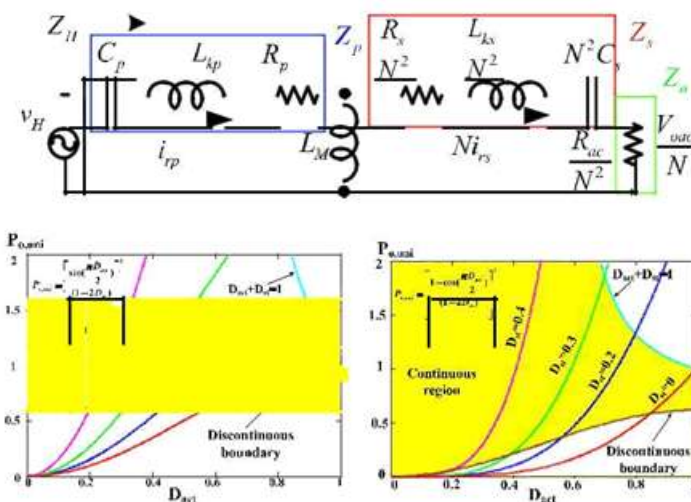




**Fig. 7.** Time domain waveforms for pulse notch control in the ZSRC. (a) Shoot-through notch and (b) zero notch.



**Fig. 8.** Control logic block inserted for pulse notch control. (a) Shoot-through notch and (b) zero notch.



**Fig. 11.** Equivalent circuit in output voltage discontinuous mode.

However, (25) is a transcendental equation and it can only be solved by numerical calculation. This discontinuous unified power curve is plotted in Fig. 13(b). The load can be regulated all the way down to zero as the black dash curve shows.

Following the same procedure, the power correction for phase-shift control is calculated and plotted in Fig. 13(a). However, its transcendental equation only has solution when  $D_{act}$  is larger than 0.5. This means phase-shift control cannot regulate the load down to zero, or the output voltage  $v_H$  is no longer a quasi-square waveform. To control the output power in continuous mode, one can follow (15) and (16). However, there is

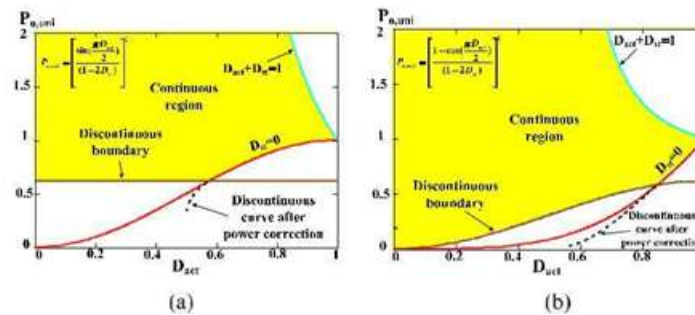


Fig. 13. Unified power curves with power correction. (a) Phase-shift control and (b) pulse notch control.

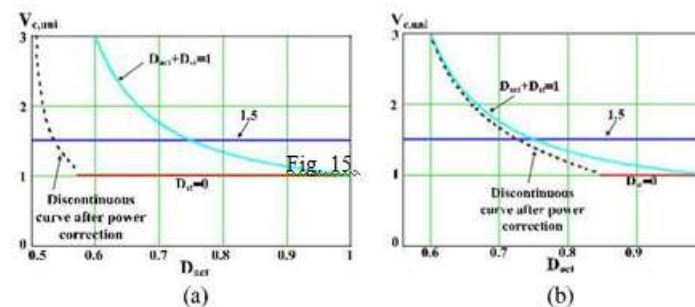


Fig. 14. Unified Z-source capacitor voltage curves for different loads corresponding to Fig. 13. (a) Phase-shift control and (b) pulse notch control.

no mathematical expression for discontinuous mode. An output power look-up table should be made offline as the dash line shown in Fig. 13. By searching the lookup table, the controller can give the actual command ( $D_{act}$ ) according to the power required.

#### D. Power Loss in a ZSRC WPT System

Different from the traditional SRC system, ZSN brings an extra shoot-through state to the H-bridge. The shoot-through state will affect both switching loss and conduction loss for the switches, especially when the ZSRC is doing hard switching.

1) *Switching Loss for H-bridge:* Both control schemes experience hard switching between different states. The switching loss depends on the voltage stress and current stress at the switching moment. For the ZSRC, the voltage stress for the H-bridge is constant ( $2V_c - V_{DC}$ ) over one switching cycle and only related to shoot-through duty cycle.

A unified Z-source capacitor voltage ( $V_{c,uni}$ ) curve for both control methods is shown in Fig. 14. The base is  $V_{DC}$ .

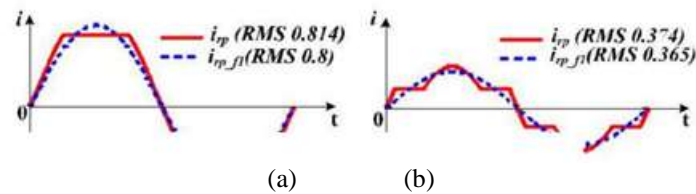
$V_{c,uni}$  increases a lot with either heavy load in light blue curve or light load in dash line. It is also reported [31] that the Z-source inverter has advantage over the boost converter plus inverter with boost ratio lower than 2, which is 1.5 for the Z-source capacitor. To avoid high voltage stress on the device, the ZSRC should be designed in the region lower than 1.5 in Fig. 14 for most load conditions.

On the other hand, the current stress for switching action depends on the instantaneous current value and the switching between specific states. Table I shows the instantaneous current difference expressions between different states during the switching action.



**Table I:** Instantaneous Current Difference Between Different States

	Active state	Zero state	Shoot-through state
Active state	0	$i_{rp} \sin(\theta)$	$i_{rp} \sin(\theta)$
Zero state	$i_{rp} \sin(\theta)$	0	$2I_L$
Shoot-through state	$2I_L - i_{rp} \sin(\theta)$	$2I_L$	0



Primary-side resonant current  $i_{rp}$  in deep discontinuous mode.

(a) Phase-shift control with  $D_{act} = 0.5$  and (b) pulse notch control with  $D_{act} = 0.56$ .

For both control methods, the upward section (larger than

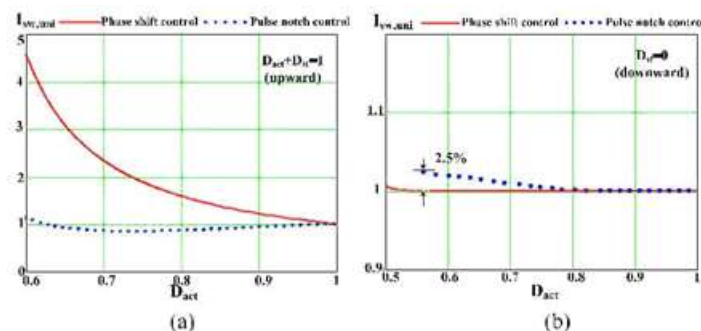
1) on power curve only has active state and shoot-through state. The switching action takes place at the peak of  $i_{rp}$  for pulse notch control, while  $i_{rp}$  is zero for phase-shift control. Therefore, pulse notch control has soft switching at the region slightly larger than 1 unit power.

When the shoot-through duty cycle is zero, the ZSRC is reduced to a traditional SRC. As the active state duty cycle decreases from 1, phase-shift control has soft switching while pulse notch control experiences hard switching at peak current. As the load further decreases, both control schemes enter discontinuous mode. Phase-shift control still has the same situation as above, since the discontinuous behavior happens in the middle of active state without any switching action. However, for pulse notch control, the discontinuous mode appears at the edge of active state and results in the switching action between shoot-through state and zero state. This is the worst case and is given in Table I, which is a drawback of pulse notch control.

2) *Conduction Loss for the Resonant Network:* As the simplified circuit shown in Fig. 9, the ZSN does not affect the resonant network characteristic. The output of H-bridge can still be modeled as a voltage source. With this voltage source, the resonant current only relates to the resonant network and the load. Therefore, the conduction loss caused by the primary-side resonant current  $i_{rp}$  is the same as the traditional H-bridge SRC system in continuous mode. As there is distortion of  $i_{rp}$  in discontinuous mode, the RMS value of  $i_{rp}$  may change and induce more conduction loss on H-bridge and winding.

3) Fig. 15 shows the distorted  $i_{rp\_f1}$  in deep discontinuous mode for both control methods. The fundamental component ( $i_{rp\_f1}$ ) of  $i_{rp}$  carries the power to the secondary side, while other harmonics circulate in primary side and cause extra conduction loss.

One can observe that even in the deepest discontinuous mode, the rms values for  $i_{rp\_f1}$  are 1.8% (phase-shift control) and 2.5% (pulse notch control) higher than that of  $i_{rp\_f1}$ . Hence, the distortion in discontinuous mode has limited effect on the conduction



**Fig. 16.** Unified switch current curves for different loads corresponding to Fig. 15. (a) For power curve larger than unit power (upward) and (b) for power curve smaller than unit power (downward).

loss. For simplification, this distortion is not considered into any theoretical calculation

3) *Conduction Loss for H-Bridge:* As given in Table I, the ZSRC switches will carry extra shoot-through current ( $2I_L$ ) compared to that of traditional SRC.



( $I_{sw,uni}$ ) with the resonant current's fundamental component as the base. One can obtain

$$i = \frac{I_{sw,uni}}{2} \quad (27)$$

As each switch in one-phase leg conducts 50% of time, the base current only considers the integration of half-cycle in (27).

Fig. 16 shows the unified switch current curves for different loads corresponding to Fig. 15. In Fig. 16(a), the shoot-through state is dominating and leads to extra loss for phase-shift control. That is because the shoot-through state happens at the absolute minimum point of the resonant current. In contrast, the shoot-through notch locates at the absolute maximum point of the resonant current, such that the extra current stress is limited. Also, pulse notch control allows all four switches to turn ON and share the shoot-through current, which further helps the conduction loss. As Fig. 16(a) shows, the  $I_{sw,uni}$  of pulse notch control even has values less than 1, and this implies that it has less conduction loss with ZSN compared to the traditional SRC.

Fig. 16(b) shows the unified switch current curves for the power less than  $P_{H,uni}$  (downward). In continuous mode, the H-bridge actually is a current chopper. As the switch action is symmetric, the current's rms value is the same as one unit. When the ZSRC enters discontinuous mode, there is current distortion as described above. However, each phase leg still behaves as a current chopper and there is limited rms increment from the distorted current in deep discontinuous mode

**Table II:** Prototype Parameters And Values

Parameters	Value	Parameters	Value
Input voltage ( $V_{dc}$ )	33 V	Primary-side compensating capacitor ( $C_p$ )	180 nF
Output	88 V/2.28 A	Primary-side leakage inductance ( $L_{kp}$ )	0.415 mH
Resonant frequency	18.2 kHz	Magnetizing inductance ( $L_M$ )	61.87 μH
Transformer turns Ratio	15:20	Secondary side leakage inductance ( $L_{ks}$ )	1.07 mH
ZSN capacitors ( $C_1, C_2$ )	4.7 mF	Secondary-side compensating capacitor ( $C_s$ )	65.8 nF
ZSN inductors ( $L_1, L_2$ )	1 mH	Output filter capacitor ( $C_o$ )	1 mF
H-bridge	6MBP100VEA120	Output rectifier	1SETH03PBF
Input diode (SiC)	GHXS020A060S		

The experimental waveforms of both control methods will be presented in next section.

#### IV. Experimental Results

The analysis and design guidelines of the proposed ZSRC system are verified based on a 200 W scale-down prototype, whose parameters are summarized in Table II.

The full-bridge output voltage  $v_H$  and primary-side resonant current  $i_{rp}$  for both control methods are shown in

Fig. 17. The ZSRC is working at full load, half-load, and ¼ load, respectively, with constant output voltage. Full load is set at a point larger than  $P_{H,uni}$ . At full load in Fig. 17(a) and (b), we can observe that the dc bus voltage  $V_z$  is higher in pulse notch control compared to phase-shift control. That is, because the power curve for phase-shift control is steeper than pulse notch control when regulating the power upward. Pulse notch control Needs more shoot-through duty cycle to maintain the same out-put power as phase-shift control does.

In terms of voltage stress on the switches, phase-shift control is better in the region larger than  $P_{H,uni}$ .

At half-load in Fig. 17(c) and (d), both control methods show similar performance in the light discontinuous mode.

Phase-shift control would have extra shoot-through state in the middle of active state. The extra shoot-through state pulse notch control merge with zero state, cannot tell the difference in  $v_H$ .

As the load further decreases, as shown in Fig. 17(e) and (f), phase-shift control has a very high voltage spike around 125 V while the pulse notch control only has a peak voltage value around 60V. For theoretical analysis, there is no solution for phase-shift control's transcendental equation at light load in Fig. 13(a), which means the waveform of phase-shift control has huge distortion and is uncontrollable.

Drawing power under such a condition results in high voltage spike. On the other hand, pulse notch control maintains quite good quality waveforms as expected.

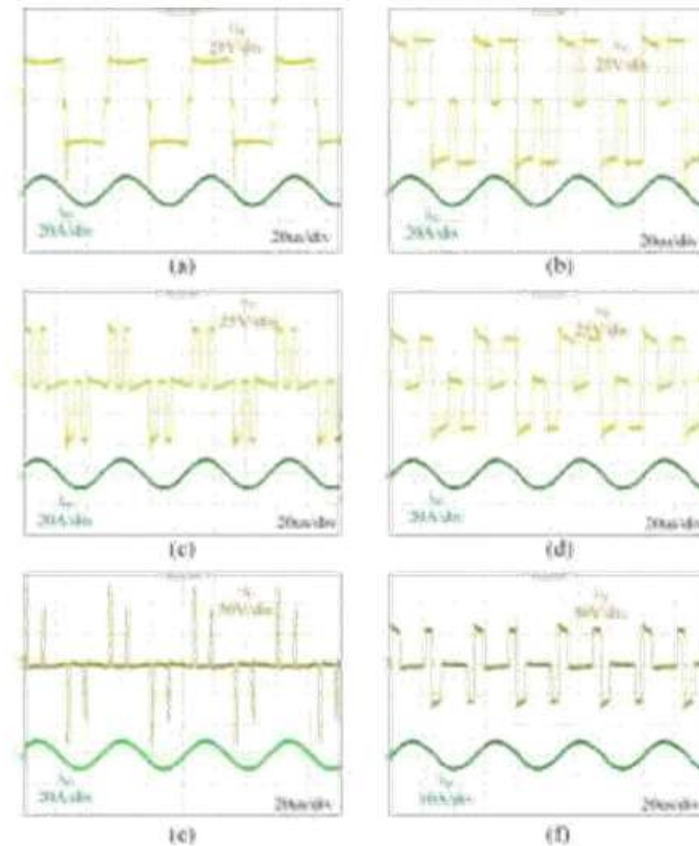


Fig. 17. Experimental waveforms of  $v_H$  and  $i_{T_p}$  ( $V_o = 88$  V, full load @  $R_L = 40 \Omega$ , half-load @  $R_L = 80 \Omega$ , and 1/4 load @  $R_L = 160 \Omega$ ).

(a) Full load, phase-shift control command  $D_{act} = 0.9$ ,  $D_{st} = 0.1$ . (b) Full load, pulse notch control command  $D_{act} = 0.78$ ,  $D_{st} = 0.22$ . (c) Half-load, phase-shift control command  $D_{act} = 0.53$ ,  $D_{st} = 0$ . (d) Half-load, pulse notch control command  $D_{act} = 0.79$ ,  $D_{st} = 0$ . (e) 1/4 load, phase-shift control command  $D_{act} = 0.47$ ,  $D_{st} = 0$ . (f) 1/4 load, pulse notch control command  $D_{act} = 0.66$ ,  $D_{st} = 0$ .

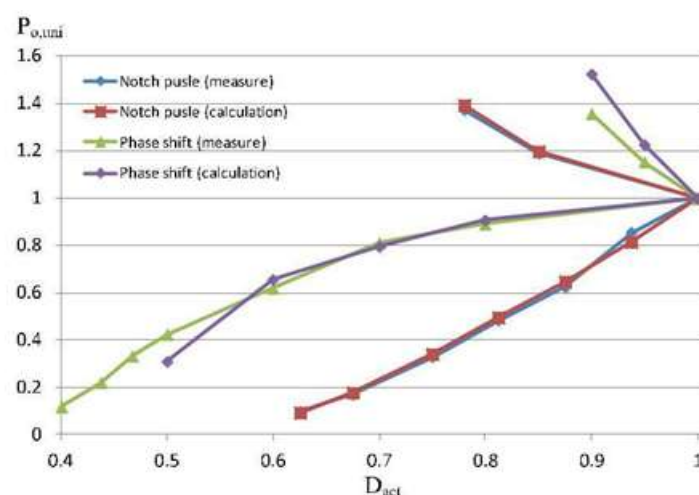


Fig. 18. Experimental unit power curve ( $R_L = 40 \Omega$ , open loop, unit power = 150 W)

discontinuous mode. For phase-shift control, it is predictable with continuous mode below  $P_{H,uni}$  and light discontinuous mode. As the upward power curve for phase-shift control is steep when regulating the power

upward, a small error in control command would be amplified. Gate signal delay difference between different switches or the turn-on and turn-off transient may cause the partial loss in shoot-through state duty cycle. These are the problems that phase-shift control has, while pulse notch control matches theoretical analysis quite well.

## V. Conclusion

This paper focuses on the load regulation methods in an SiC-based ZSRC for WPT application. Two constant frequency control methods, phase-shift control and pulse notch control, are presented with comparison on load regulation performance. Phase-shift control is easier in implementation but it suffers from high distortion at light load in discontinuous mode. On the other hand, pulse notch control is more predictable than phase-shift control over the entire load range. However, both control methods are doing hard switching, which is a drawback for the ZSRC. Fortunately, it does not have much switching loss since the switching frequency is less than 20 kHz in this WPT application. Experimental results based on a 200-W scale-down prototype with the ZSRC are presented. For future work, these two control methods can be applied for PFC and load regulation at the same time in the ZSRC that leads to a single-stage solution for an EV charger. Pulse notch control is a better candidate for PFC function to achieve high power factor. Also, soft switching techniques will be examined on the ZSRC.

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